**ON Semiconductor** 

Is Now

# Onsemi

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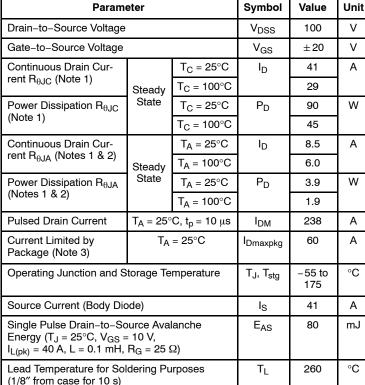
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# MOSFET – Power, Single **N-Channel 100 V, 20 mΩ, 41 A**

#### Features

- Low R<sub>DS(on)</sub> to Minimize Conduction Losses
- High Current Capability
- Avalanche Energy Specified
- AEC-Q101 Qualified
- These Devices are Pb-Free, Halogen Free/BFR Free and are RoHS Compliant

#### MAXIMUM RATINGS (T<sub>J</sub> = 25°C unless otherwise noted) Parameter Symbol



Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

#### THERMAL RESISTANCE MAXIMUM RATINGS

Parameter	Symbol	Value	Unit
Junction-to-Case - Steady State (Drain)	$R_{\theta JC}$	1.7	°C/W
Junction-to-Ambient - Steady State (Note 2)	$R_{\theta JA}$	39	

The entire application environment impacts the thermal resistance values 1. shown, they are not constants and are only valid for the particular conditions noted.

2. Surface-mounted on FR4 board using a 650 mm<sup>2</sup>, 2 oz. Cu pad.

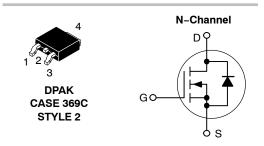
Continuous DC current rating. Maximum current for pulses as long as 1 3. second is higher but is dependent on pulse duration and duty cycle.



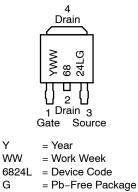
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V <sub>(BR)DSS</sub>	R <sub>DS(on)</sub>	I <sub>D</sub>
100 V	$20\mathrm{m}\Omega\ensuremath{@}10\mathrm{V}$	41 A
	23 mΩ @ 4.5 V	ТТ







#### **ORDERING INFORMATION**

Device	Package	Shipping <sup>†</sup>
NVD6824NLT4G	DPAK (Pb–Free)	2500/Tape & Reel
NVD6824NLT4G-VF01	DPAK (Pb–Free)	2500/Tape & Reel

+For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

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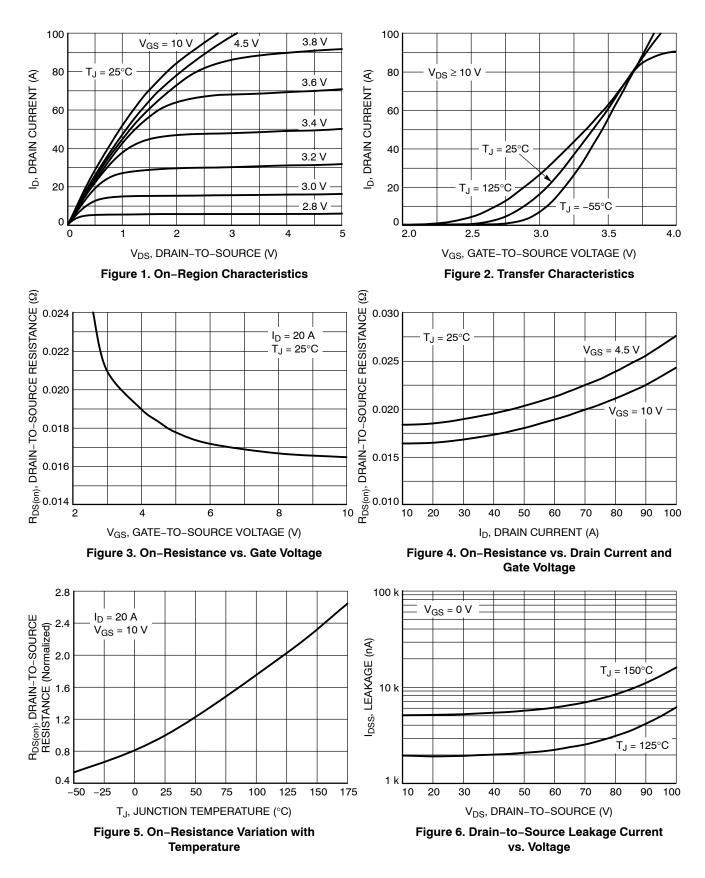
## **ELECTRICAL CHARACTERISTICS** (T<sub>J</sub> = $25^{\circ}C$ unless otherwise noted)

Parameter	Symbol	Test Condition		Min	Тур	Max	Unit
OFF CHARACTERISTICS	· · ·				-	-	•
Drain-to-Source Breakdown Voltage	V <sub>(BR)DSS</sub>	$V_{GS}$ = 0 V, I <sub>D</sub> = 250 µA		100			V
Drain-to-Source Breakdown Voltage Temperature Coefficient	V <sub>(BR)DSS</sub> /T <sub>J</sub>				92		mV/°C
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	V <sub>GS</sub> = 0 V,	$T_J = 25^{\circ}C$			1.0	μA
		$V_{DS} = 100 V$	T <sub>J</sub> = 125°C			100	
Gate-to-Source Leakage Current	I <sub>GSS</sub>	$V_{DS} = 0 V, V_{GS} = \pm 20 V$				±100	nA
ON CHARACTERISTICS (Note 4)							
Gate Threshold Voltage	V <sub>GS(TH)</sub>	$V_{GS} = V_{DS}, I_D =$	= 250 μA	1.5		2.5	V
Negative Threshold Temperature Co- efficient	V <sub>GS(TH)</sub> /T <sub>J</sub>				-6.5		mV/°C
Drain-to-Source On Resistance	R <sub>DS(on)</sub>	$V_{GS}$ = 10 V, I <sub>D</sub> = 20 A $V_{GS}$ = 4.5 V, I <sub>D</sub> = 20 A			16.5	20	mΩ
					18.5	23	1
Forward Transconductance	gFS	V <sub>DS</sub> = 15 V, I <sub>D</sub> = 20 A			18		S
CHARGES, CAPACITANCES AND GA	TE RESISTANCE	S					
Input Capacitance	C <sub>iss</sub>	V <sub>GS</sub> = 0 V, f = 1.0 MHz, V <sub>DS</sub> = 25 V			3468		pF
Output Capacitance	C <sub>oss</sub>				187		-
Reverse Transfer Capacitance	C <sub>rss</sub>				133		
Total Gate Charge	tal Gate Charge $ \begin{array}{c} Q_{G(\text{TOT})} \\ I_D = 20 \ \text{A} \end{array} V_{\text{GS}} = 4.5 \ \text{V}, \ V_{\text{DS}} = 80 \ \text{V}, \\ \\ I_D = 20 \ \text{A} \end{array} V_{\text{GS}} V$	<sub>IS</sub> = 80 V, A		34		nC	
		$V_{GS}$ = 10 V, $V_{DS}$ = 80 V, I <sub>D</sub> = 20 A			66		
Threshold Gate Charge	Q <sub>G(TH)</sub>	$V_{GS}$ = 10 V, $V_{DS}$ = 80 V, I <sub>D</sub> = 20 A			3.5		
Gate-to-Source Charge	Q <sub>GS</sub>				9.0		1
Gate-to-Drain Charge	Q <sub>GD</sub>				18		
SWITCHING CHARACTERISTICS (Not	e 5)						
Turn-On Delay Time	t <sub>d(on)</sub>	$V_{GS}$ = 10 V, $V_{DD}$ = 80 V, $I_{D}$ = 20 A, $R_{G}$ = 2.5 $\Omega$			15		ns
Rise Time	t <sub>r</sub>				55		]
Turn-Off Delay Time	t <sub>d(off)</sub>				31		
Fall Time	t <sub>f</sub>				42		
DRAIN-SOURCE DIODE CHARACTER	RISTICS						
Forward Diode Voltage	V <sub>SD</sub> V <sub>GS</sub>	$V_{GS} = 0 V,$	$T_J = 25^{\circ}C$		0.84	1.2	V
		I <sub>S</sub> = 20 A	T <sub>J</sub> = 125°C		0.71		
Reverse Recovery Time	t <sub>RR</sub>	V <sub>GS</sub> = 0 V, dls/dt = 100 A/μs, I <sub>S</sub> = 20 A			38		ns
Charge Time	ta				28		
Discharge Time	tb				10		1
Reverse Recovery Charge	Q <sub>RR</sub>				59		nC

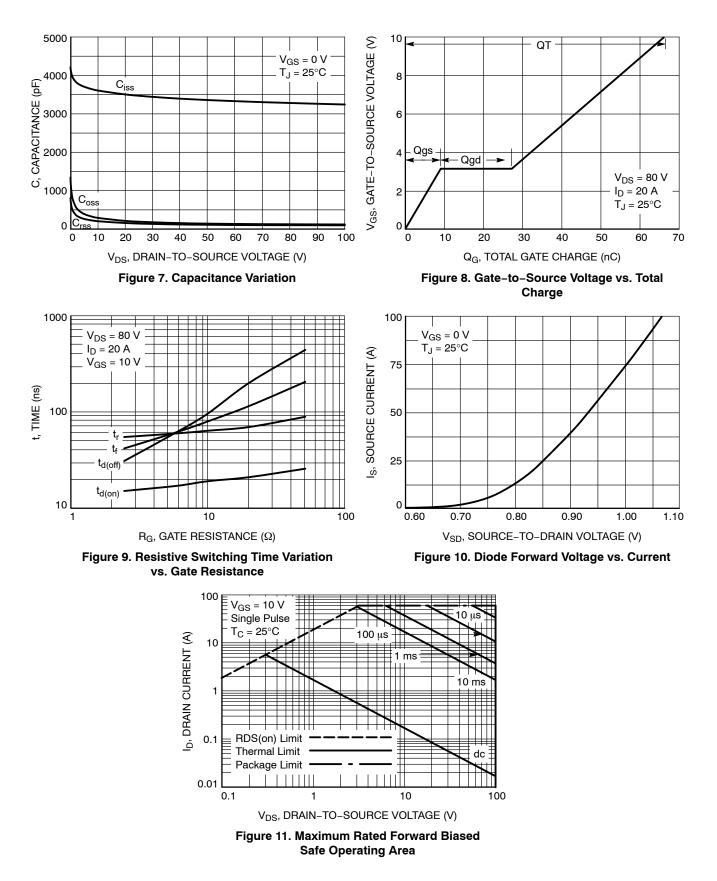
Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

4. Pulse Test: Pulse Width  $\leq$  300  $\mu$ s, Duty Cycle  $\leq$  2%. 5. Switching characteristics are independent of operating junction temperatures.

#### **TYPICAL CHARACTERISTICS**



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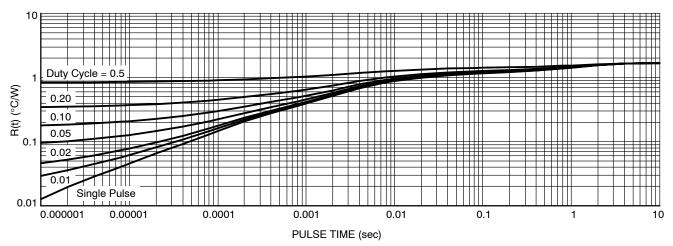
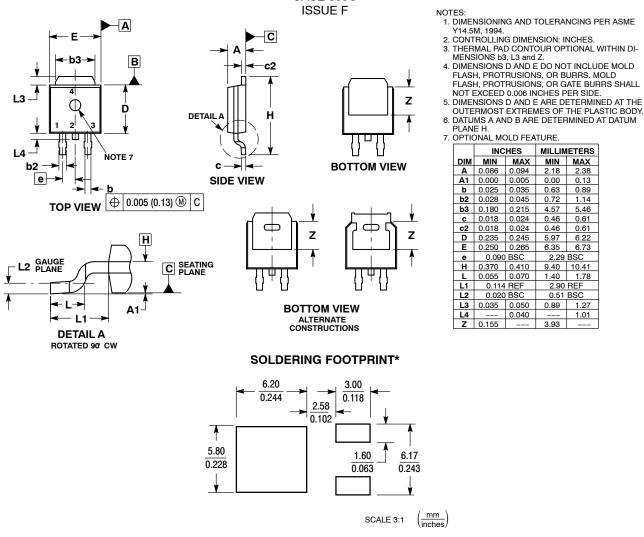


Figure 12. Thermal Response

#### PACKAGE DIMENSIONS

**DPAK (SINGLE GAUGE)** CASE 369C



\*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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